

# KO DELPS1.22

## TOPLED® E1608

The TOPLED E1608 expands OSRAM Opto Semiconductors' low power portfolio by offering one of the smallest LED Industry standard footprints in a highly reliable and well proved package concept.

Its outstanding performance is suitable for a huge variety of applications especially automotive interior where a small package design with excellent reliability is needed. The TOPLED E1608 is available in different colors and brightness levels.



## Applications

- Cluster, Button Backlighting
- Electronic Equipment
- Interior Illumination e.g. Ambient Map

## Features:

- Package: white SMT package, colorless clear resin
- Chip technology: Thinfilm
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{\text{dom}} = 606 \text{ nm}$  (• orange)
- Corrosion Robustness Class: 1B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

## Ordering Information

Type	Luminous Intensity <sup>1)</sup> $I_F = 20 \text{ mA}$ $I_v$	Ordering Code
KO DELPS1.22-UGVI-24-H3Q4	450 ... 1120 mcd	Q65112A3997

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## Maximum Ratings

Parameter	Symbol		Values
Operating Temperature	$T_{op}$	min.	-40 °C
		max.	110 °C
Storage Temperature	$T_{stg}$	min.	-40 °C
		max.	110 °C
Junction Temperature	$T_j$	max.	125 °C
Forward current $T_s = 25\text{ °C}$	$I_F$	min.	1 mA
		max.	30 mA
Surge Current $t \leq 10\ \mu\text{s}$ ; $D = 0.005$ ; $T_s = 25\text{ °C}$	$I_{FS}$	max.	70 mA
Reverse voltage <sup>2)</sup> $T_s = 25\text{ °C}$	$V_R$	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$		2 kV

## Characteristics

$I_F = 20 \text{ mA}$ ;  $T_s = 25 \text{ °C}$

Parameter	Symbol		Values
Peak Wavelength	$\lambda_{\text{peak}}$	typ.	610 nm
Dominant Wavelength <sup>3)</sup> $I_F = 20 \text{ mA}$	$\lambda_{\text{dom}}$	min.	600 nm
		typ.	606 nm
		max.	609 nm
Spectral Bandwidth at 50% $I_{\text{rel,max}}$	$\Delta\lambda$	typ.	17 nm
Viewing angle at 50 % $I_V$	$2\varphi$	typ.	120 °
Forward Voltage <sup>4)</sup> $I_F = 20 \text{ mA}$	$V_F$	min.	1.95 V
		typ.	2.30 V
		max.	2.50 V
Reverse current <sup>2)</sup> $V_R = 12 \text{ V}$	$I_R$	typ.	0.01 $\mu\text{A}$
		max.	10 $\mu\text{A}$
Temperature Coefficient of Peak Wavelength $-10\text{°C} \leq T \leq 100\text{°C}$	$\text{TC}_{\lambda_{\text{peak}}}$	typ.	0.14 nm / K
Real thermal resistance junction/solderpoint <sup>5)</sup>	$R_{\text{thJS real}}$	typ.	120 K / W
		max.	150 K / W

## Brightness Groups

Group	Luminous Intensity <sup>1)</sup> $I_F = 20 \text{ mA}$ min. $I_v$	Luminous Intensity <sup>1)</sup> $I_F = 20 \text{ mA}$ max. $I_v$	Luminous Flux <sup>6)</sup> $I_F = 20 \text{ mA}$ typ. $\Phi_v$
UG	450 mcd	520 mcd	1600 mlm
UH	520 mcd	610 mcd	1900 mlm
UI	610 mcd	710 mcd	2200 mlm
VG	710 mcd	820 mcd	2500 mlm
VH	820 mcd	970 mcd	3000 mlm
VI	970 mcd	1120 mcd	3400 mlm

## Forward Voltage Groups

Group	Forward Voltage <sup>4)</sup> $I_F = 20 \text{ mA}$ min. $V_F$	Forward Voltage <sup>4)</sup> $I_F = 20 \text{ mA}$ max. $V_F$
H3	1.95 V	2.10 V
L4	2.10 V	2.30 V
Q4	2.30 V	2.50 V

## Wavelength Groups

Group	Dominant Wavelength <sup>3)</sup> $I_F = 20 \text{ mA}$ min. $\lambda_{\text{dom}}$	Dominant Wavelength <sup>3)</sup> $I_F = 20 \text{ mA}$ max. $\lambda_{\text{dom}}$
2	600 nm	603 nm
3	603 nm	606 nm
4	606 nm	609 nm

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## Group Name on Label

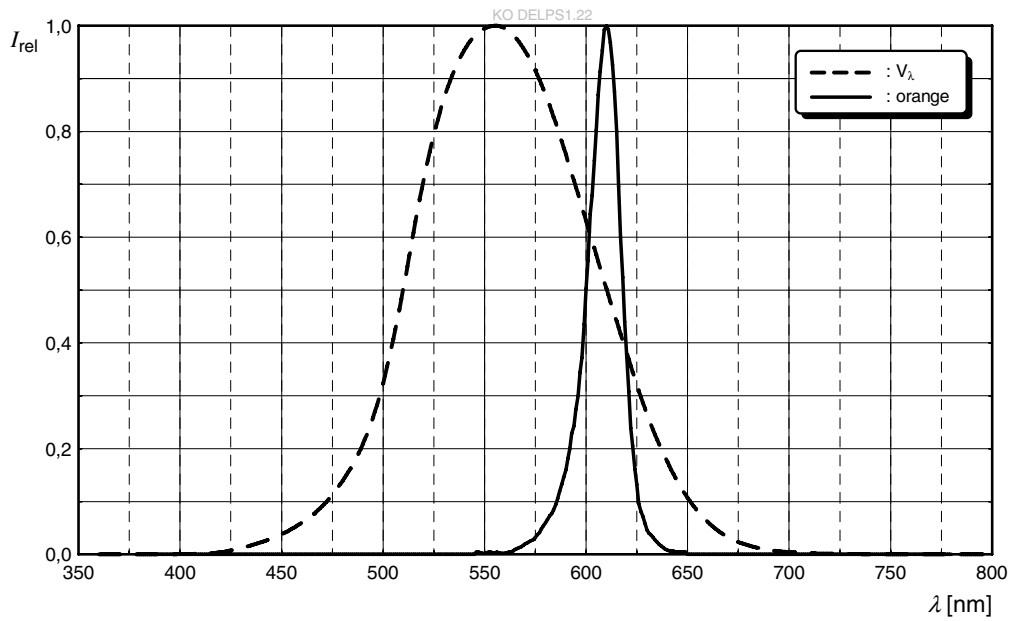
**Example: UG-2-H3**

Brightness	Wavelength	Forward Voltage
UG	2	H3

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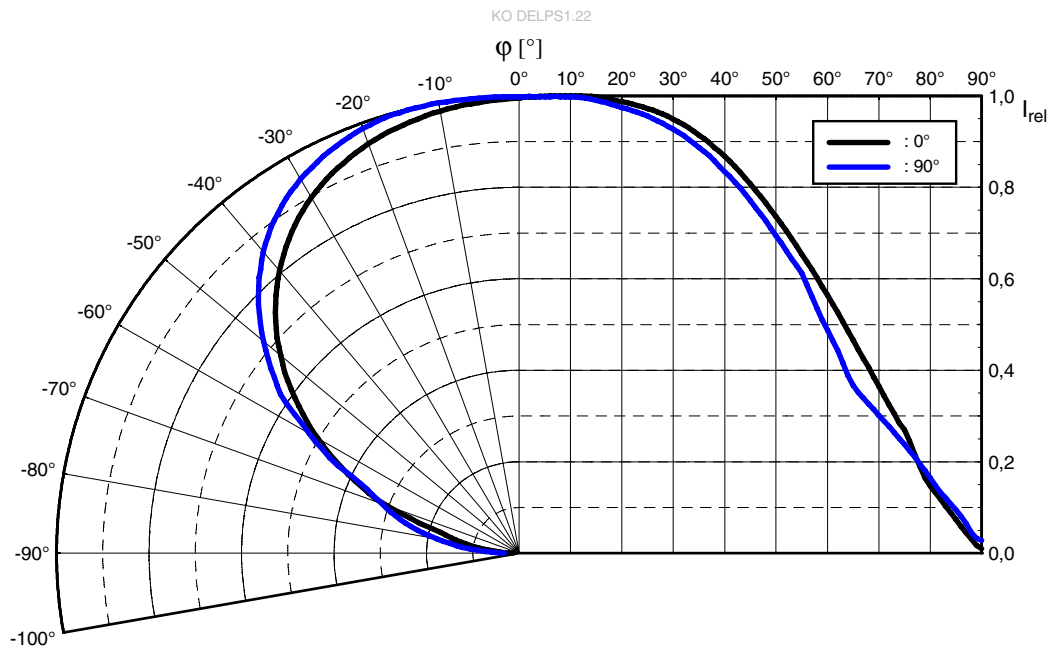
### Relative Spectral Emission <sup>6)</sup>

$I_{rel} = f(\lambda)$ ;  $I_F = 20 \text{ mA}$ ;  $T_S = 25 \text{ }^\circ\text{C}$



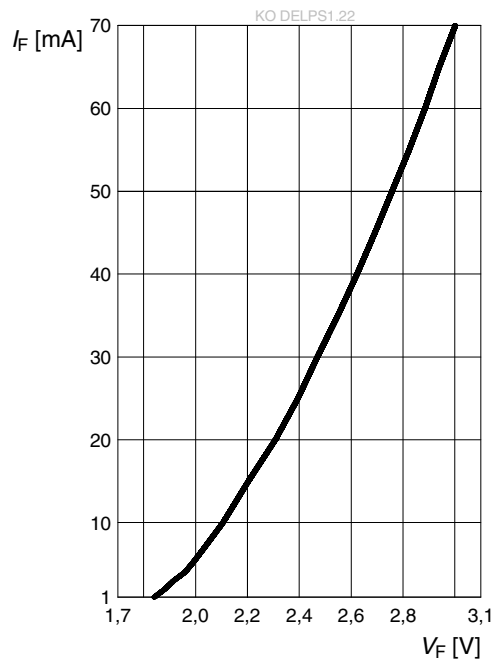
### Radiation Characteristics <sup>6)</sup>

$I_{rel} = f(\phi)$ ;  $T_S = 25 \text{ }^\circ\text{C}$



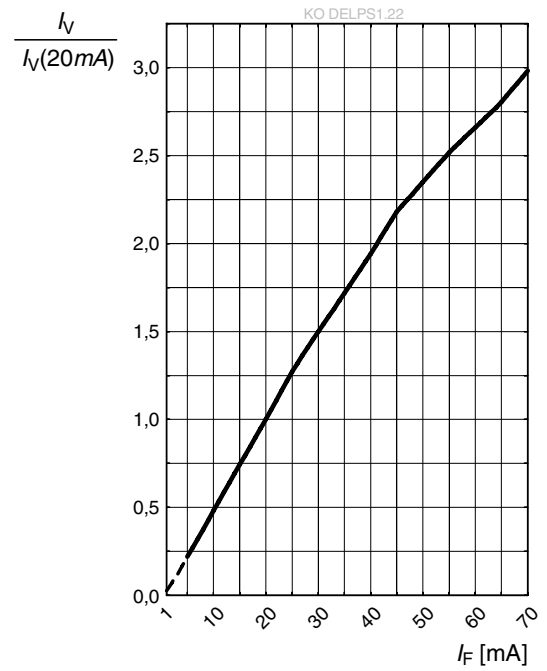
**Forward current** <sup>6), 7)</sup>

$I_F = f(V_F); T_S = 25\text{ °C}$



**Relative Luminous Intensity** <sup>6), 7)</sup>

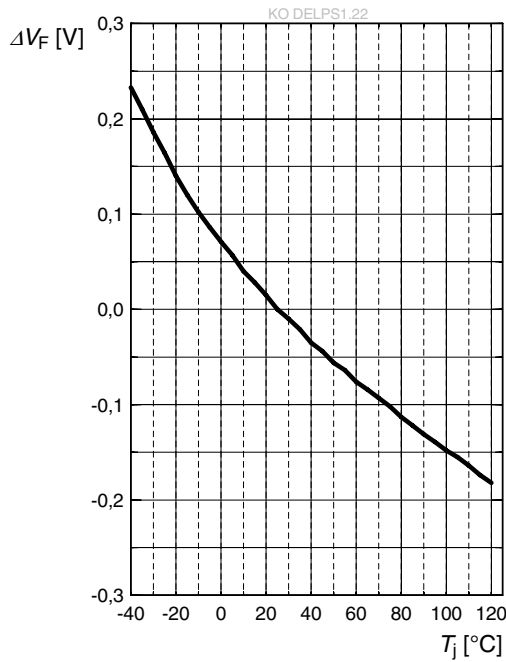
$I_V/I_V(20\text{ mA}) = f(I_F); T_S = 25\text{ °C}$





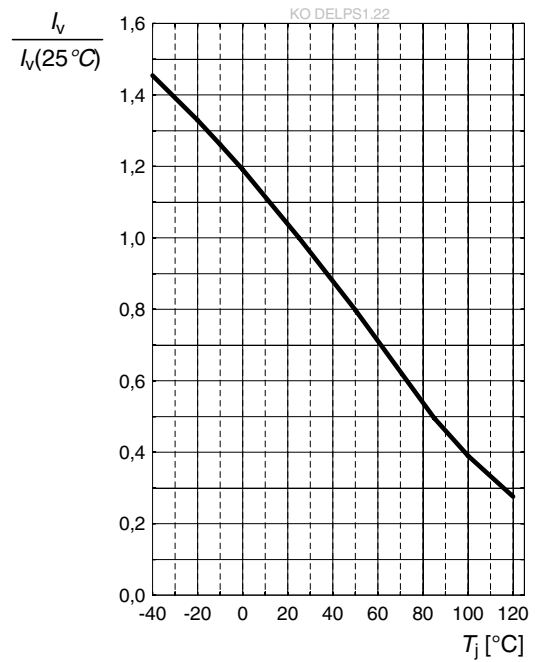
### Forward Voltage <sup>6)</sup>

$$\Delta V_F = V_F - V_F(25\text{ °C}) = f(T_j); I_F = 20\text{ mA}$$



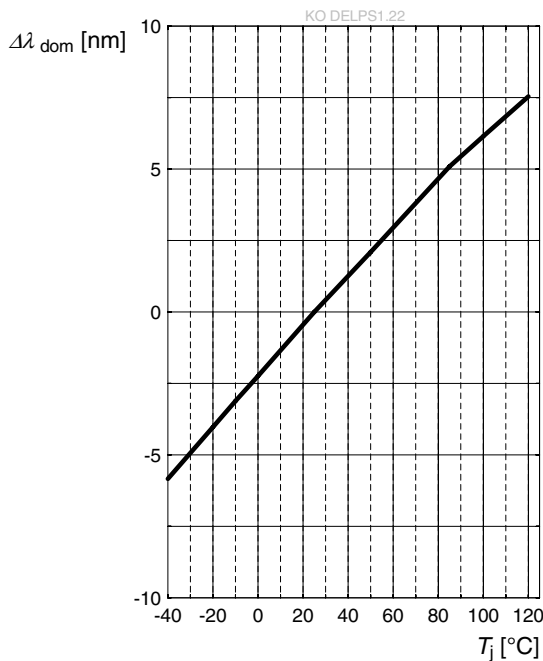
### Relative Luminous Intensity <sup>6)</sup>

$$I_V/I_V(25\text{ °C}) = f(T_j); I_F = 20\text{ mA}$$



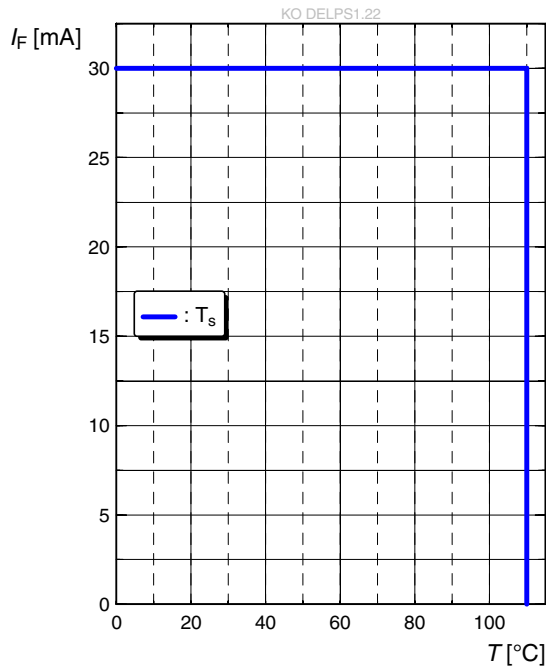
### Dominant Wavelength <sup>6)</sup>

$$\Delta \lambda_{\text{dom}} = \lambda_{\text{dom}} - \lambda_{\text{dom}}(25\text{ °C}) = f(T_j); I_F = 20\text{ mA}$$



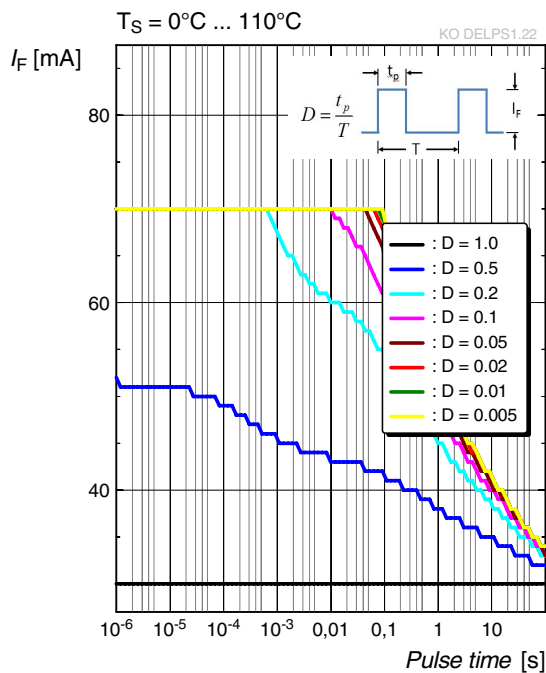
## Max. Permissible Forward Current

$$I_F = f(T)$$

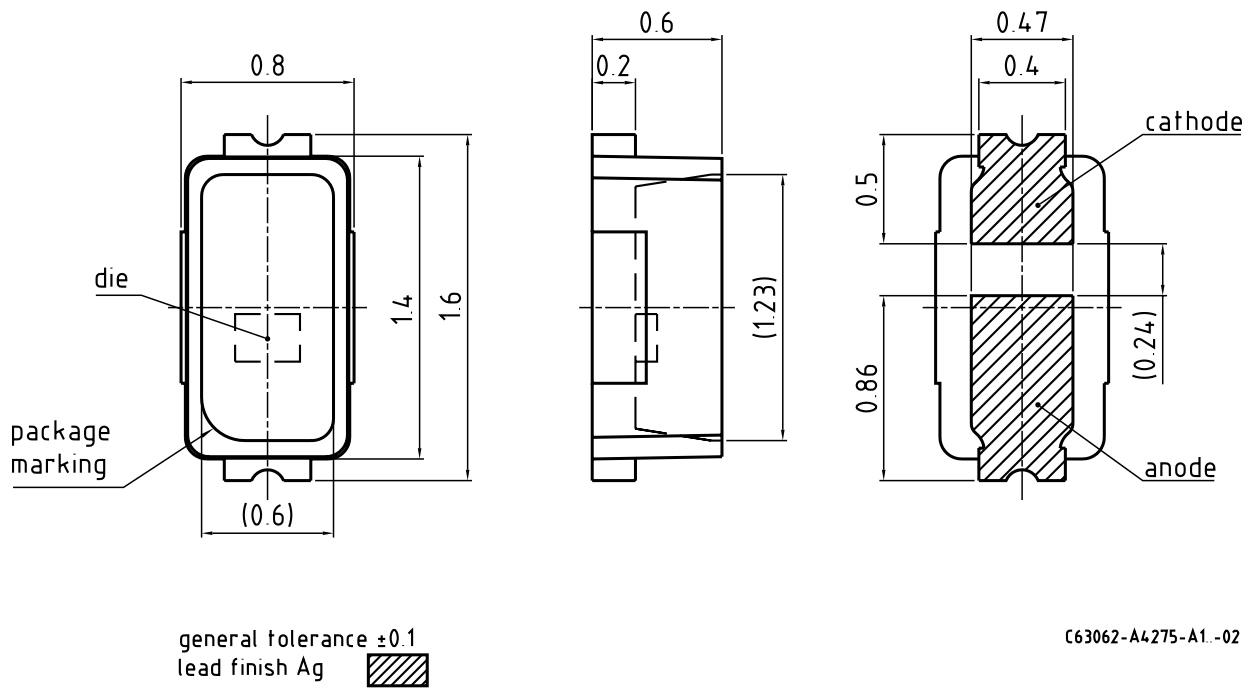


## Permissible Pulse Handling Capability

$$I_F = f(t_p); D: \text{Duty cycle}$$



**Dimensional Drawing** <sup>8)</sup>



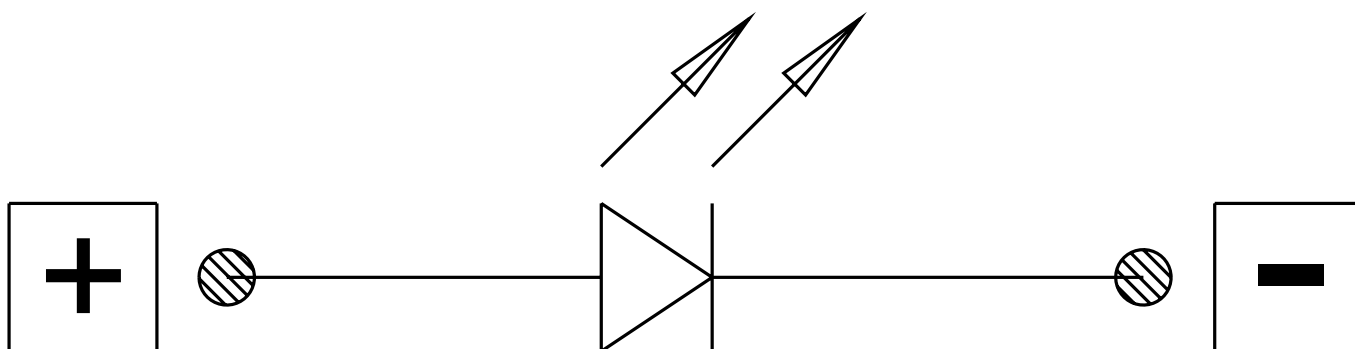
**Approximate Weight:** 2.0 mg

**Package marking:** Anode

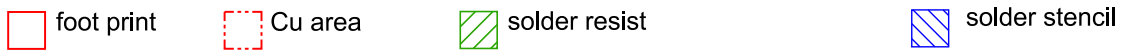
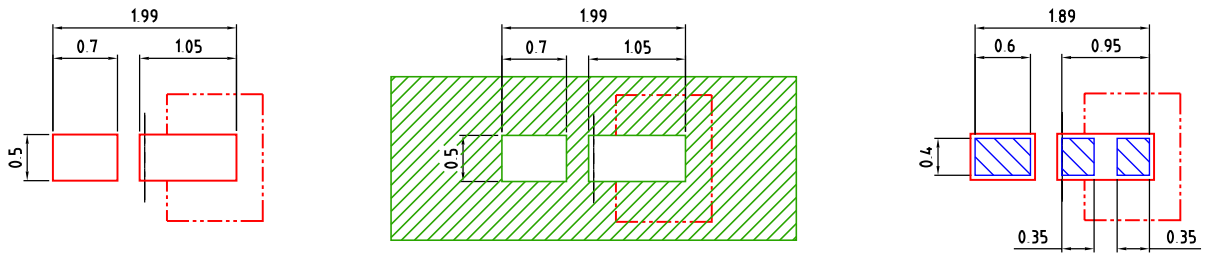
**Corrosion test:** Class: 1B  
 Test condition: 25°C / 75 % RH / 200ppb SO<sub>2</sub>, 200ppb NO<sub>2</sub>, 10ppb H<sub>2</sub>S,  
 10ppb Cl<sub>2</sub> / 21 days (EN 60068-2-60 (Method 4))

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## Electrical internal circuit

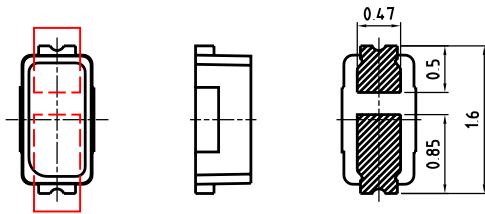


## Recommended Solder Pad <sup>8)</sup>



The usage of solder resist between anode and cathode pads is mandatory for applications where water may condense

### Component Location on Pad

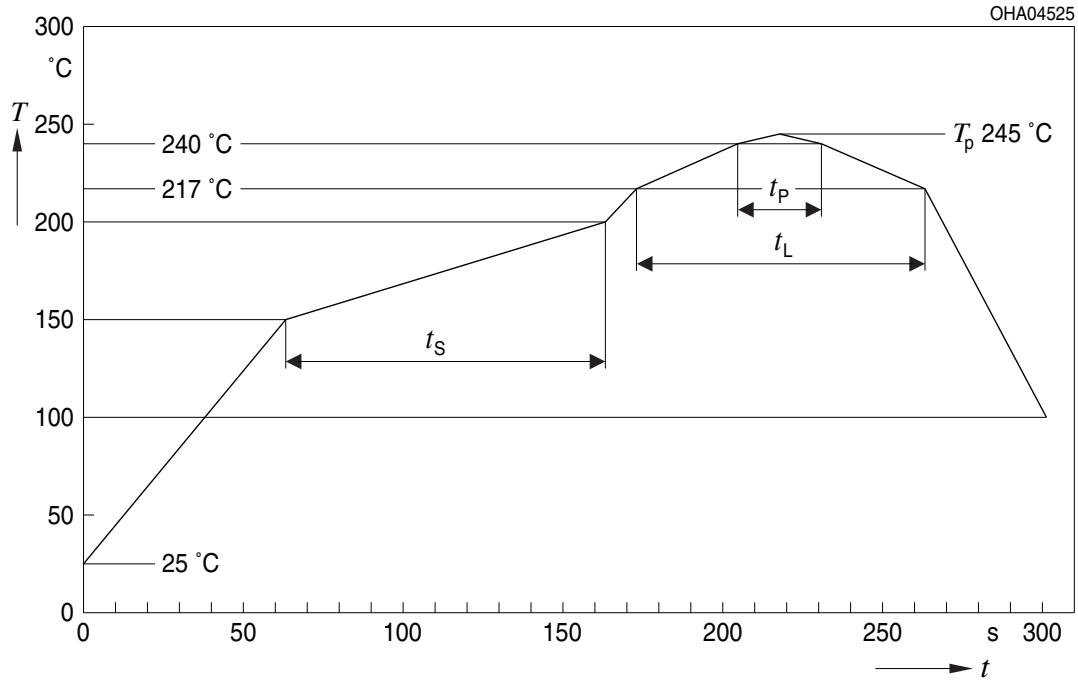


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For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere.

## Reflow Soldering Profile

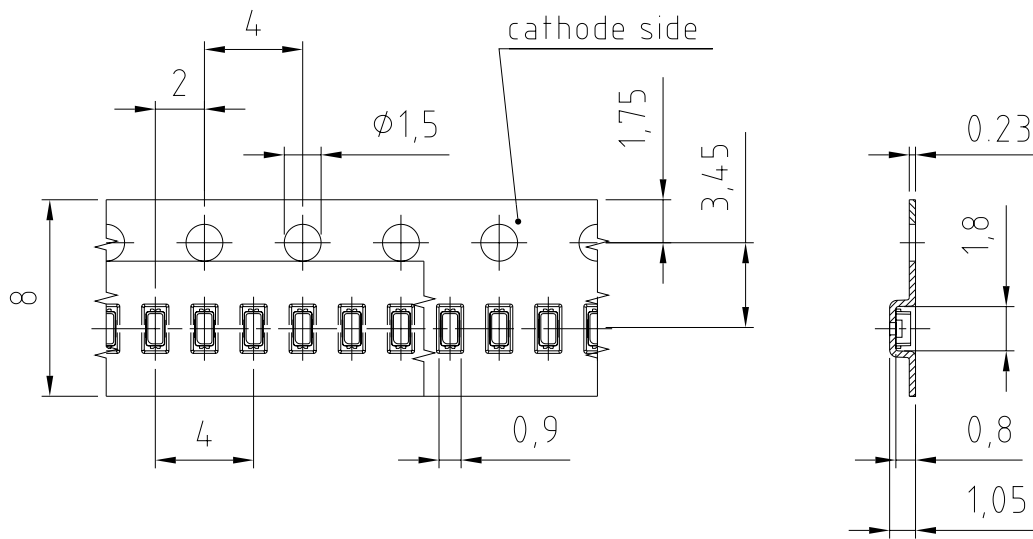
Product complies to MSL Level 3 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time $t_s$ $T_{Smin}$ to $T_{Smax}$	$t_s$	60	100	120	s
Ramp-up rate to peak*) $T_{Smax}$ to $T_p$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_p$		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5$ K	$t_p$	10	20	30	s
Ramp-down rate* $T_p$ to 100 °C			3	6	K/s
Time 25 °C to $T_p$				480	s

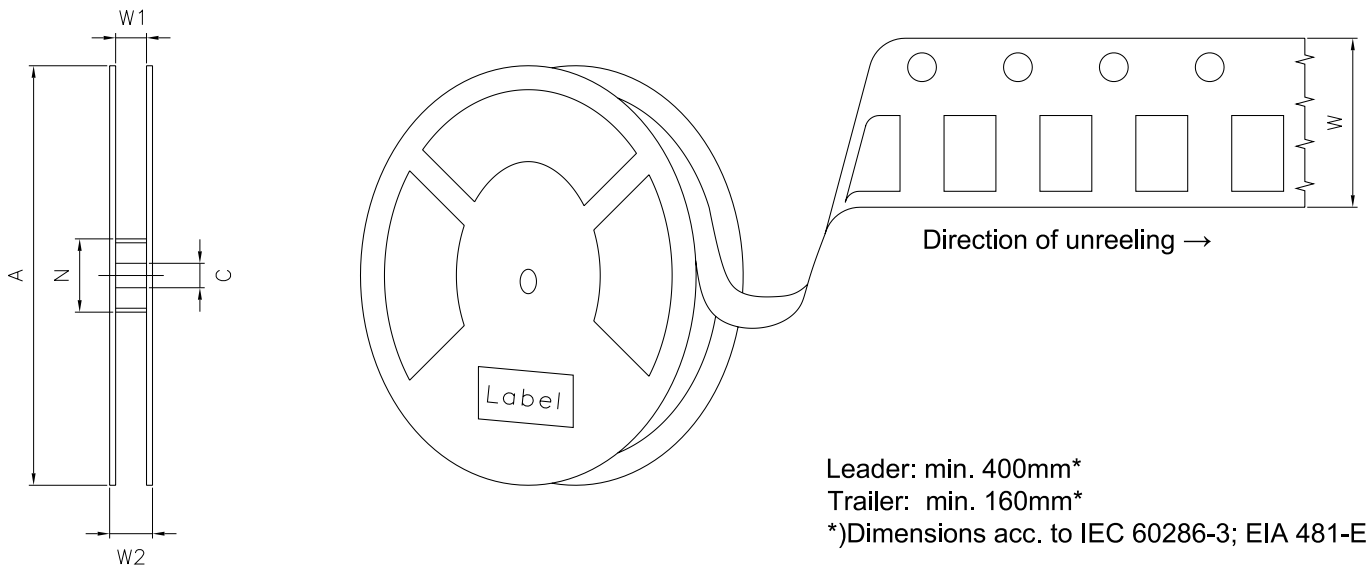
All temperatures refer to the center of the package, measured on the top of the component  
 \*) slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range

**Taping** <sup>8)</sup>



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**Tape and Reel** <sup>9)</sup>

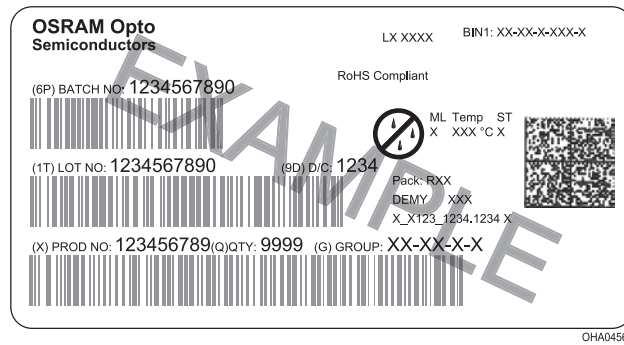


**Reel dimensions [mm]**

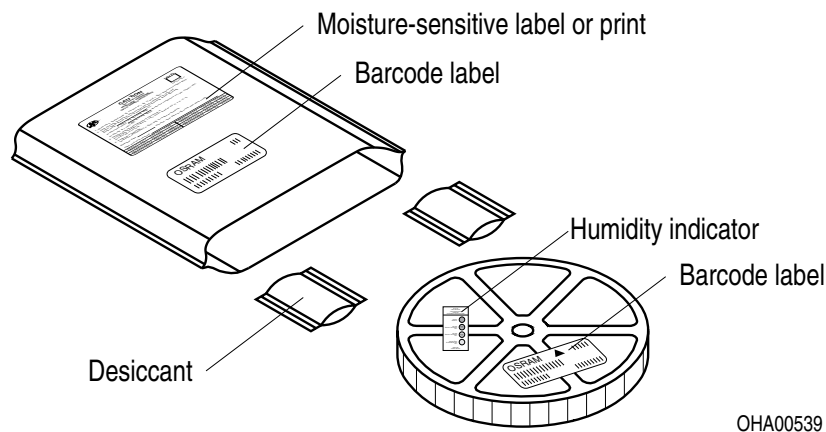
A	W	N <sub>min</sub>	W <sub>1</sub>	W <sub>2 max</sub>	Pieces per PU
180 mm	8 + 0.3 / - 0.1	60	8.4 + 2	14.4	5000



## Barcode-Product-Label (BPL)

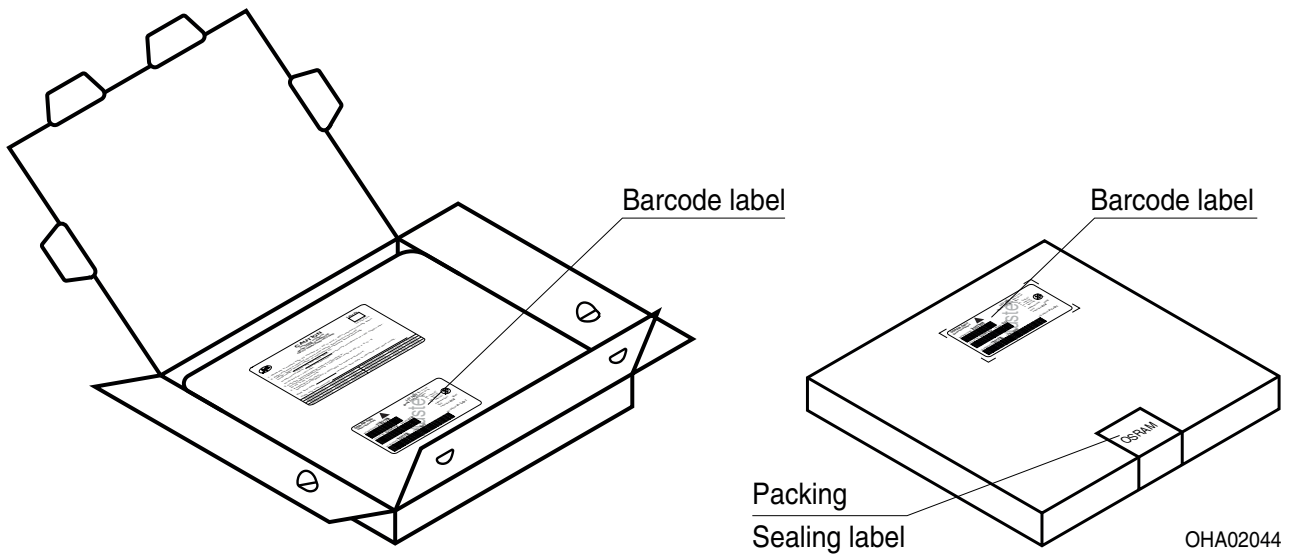


## Dry Packing Process and Materials <sup>8)</sup>



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

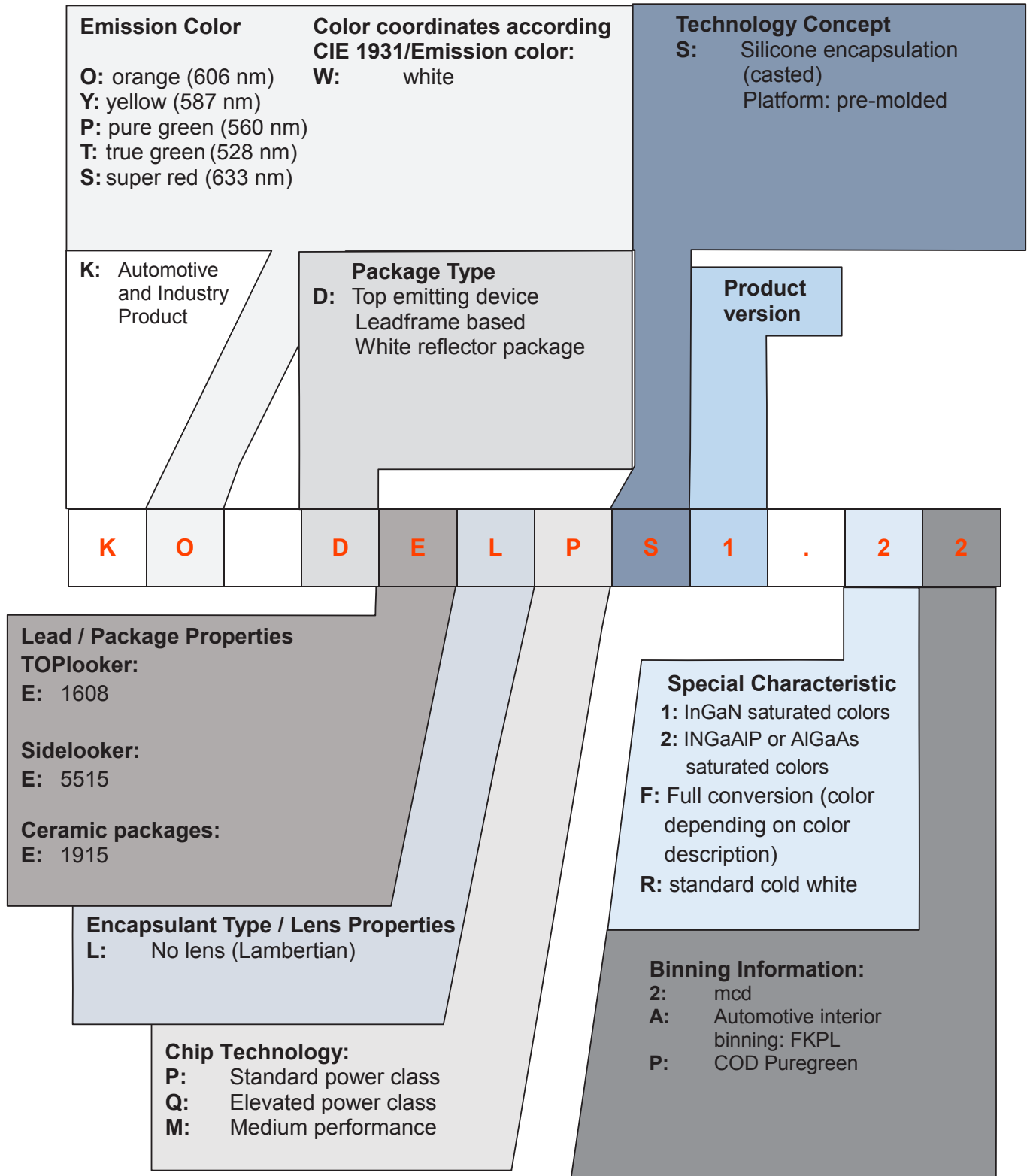
## Transportation Packing and Materials <sup>8)</sup>



### Dimensions of transportation box in mm

Width	Length	Height
200 ± 5 mm	195 ± 5 mm	30 ± 5 mm

## Type Designation System



## Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the LED specified in this data sheet fall into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this LED contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize LED exposure to aggressive substances during storage, production, and use. LEDs that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit [www.osram-os.com/appnotes](http://www.osram-os.com/appnotes)

## Disclaimer

### Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.

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## Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 8\%$  and an expanded uncertainty of  $\pm 11\%$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 2) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 3) **Wavelength:** The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 0.5$  nm and an expanded uncertainty of  $\pm 1$  nm (acc. to GUM with a coverage factor of  $k = 3$ ).
- 4) **Forward Voltage:** The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of  $\pm 0.05$  V and an expanded uncertainty of  $\pm 0.1$  V (acc. to GUM with a coverage factor of  $k = 3$ ).
- 5) **Thermal Resistance:**  $R_{th\ max}$  is based on statistic values ( $6\sigma$ ).
- 6) **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 7) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single LEDs within one packing unit.
- 8) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with  $\pm 0.1$  and dimensions are specified in mm.
- 9) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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